

# 2SA1096, 2SA1096A

## Silicon PNP epitaxial planar type

For low-frequency power amplification

Complementary to 2SC2497, 2SC2497A

### ■ Features

- Output of 5 W can be obtained by a complementary pair with 2SC2497 and 2SC2497A
- TO-126B package which requires no insulation plate for installation to the heat sink

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	-70	V
Collector-emitter voltage (Base open)	2SA1096	$V_{CEO}$	-50
	2SA1096A		-60
Emitter-base voltage (Collector open)	$V_{EBO}$	-5	V
Collector current	$I_C$	-2	A
Peak collector current	$I_{CP}$	-3	A
Collector power dissipation	$P_C$	1.2	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

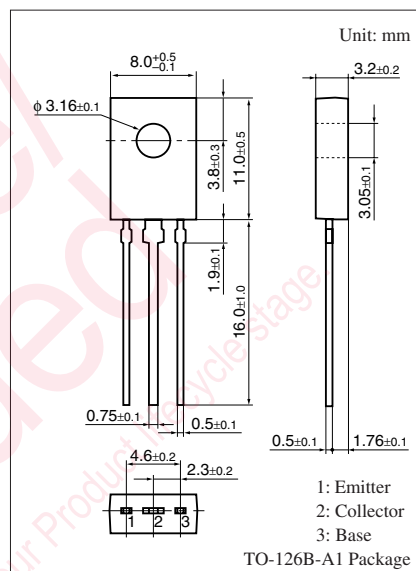
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_C = -1 \text{ mA}, I_E = 0$	-70			V
Collector-emitter voltage (Base open)	2SA1096	$I_C = -2 \text{ mA}, I_B = 0$	-50			V
	2SA1096A		-60			
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -20 \text{ V}, I_E = 0$			-1	$\mu\text{A}$
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = -10 \text{ V}, I_B = 0$			-100	$\mu\text{A}$
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = -5 \text{ V}, I_C = 0$			-10	$\mu\text{A}$
Forward current transfer ratio <sup>*1,2</sup>	$h_{FE}$	$V_{CE} = -5 \text{ V}, I_C = -1 \text{ A}$	80		220	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1.5 \text{ A}, I_B = -0.15 \text{ A}$			-1	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -1.5 \text{ A}, I_B = -0.15 \text{ A}$			-1.5	V
Transition frequency	$f_T$	$V_{CB} = -5 \text{ V}, I_E = 0.5 \text{ A}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance (Common base, input open circuited)	$C_{ob}$	$V_{CB} = -20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		55		pF

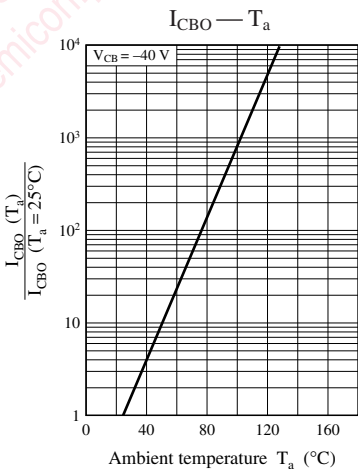
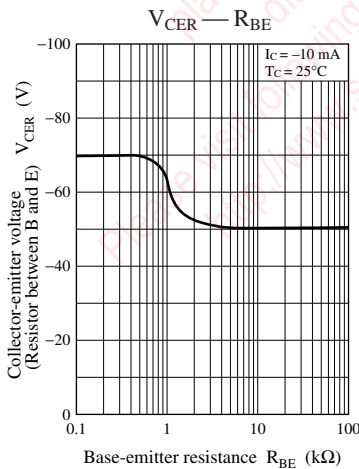
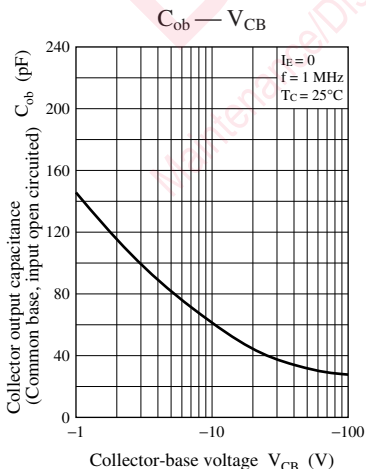
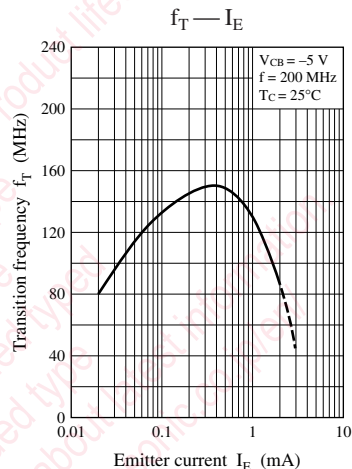
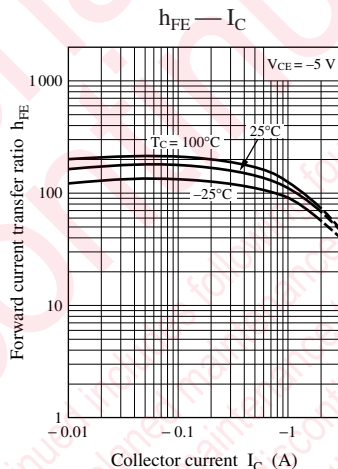
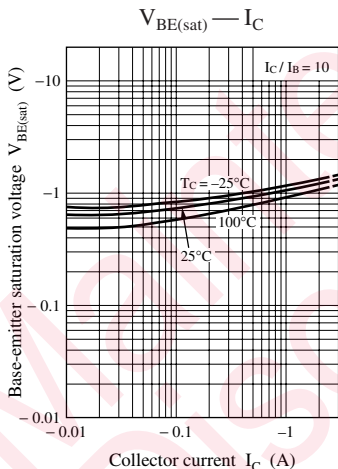
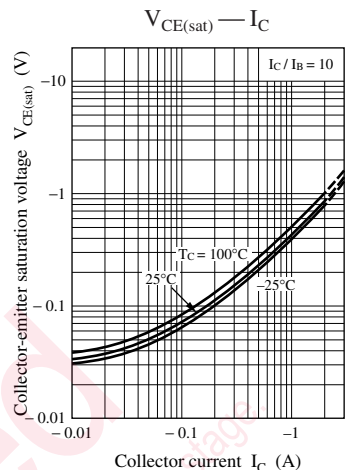
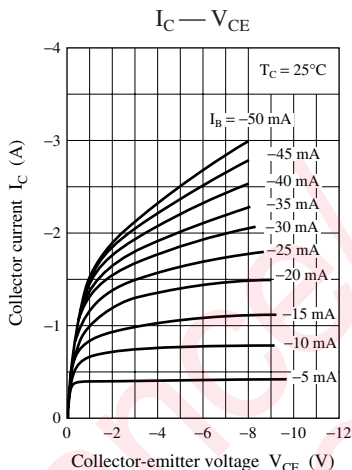
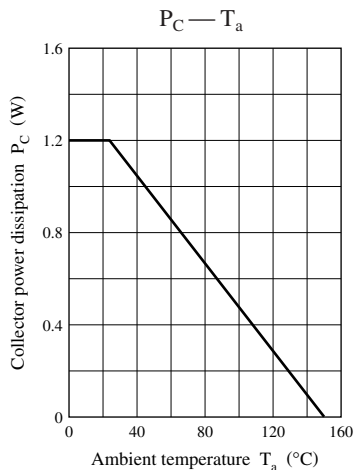
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

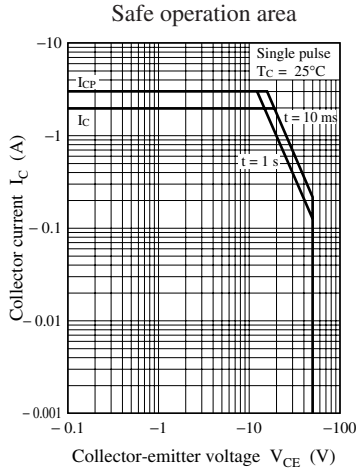
2. \*1: Pulse measurement

\*2: Rank classification

Rank	Q	R
$h_{FE}$	80 to 160	120 to 220







Maintenance/Discontinued

Maintenance/Discontinued includes following four Product lifecycle stage.

- planned maintenance type
- maintenance type
- planned discontinued type
- discontinued type

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